## **NUR460**

# Ultrafast power diode Rev. 2 — 20 July 2011

Product data sheet

#### **Product profile** 1.

## 1.1 General description

Ultrafast epitaxial power diode in a SOD141 (DO-201AD) axial lead plastic package.

### 1.2 Features and benefits

- Axial leaded plastic package
- Fast switching
- High voltage capability

- Low forward voltage drop
- Low thermal resistance
- Soft recovery characteristic

## 1.3 Applications

■ Discontinuous Current Mode (DCM) Power Factor Correction (PFC)

■ High frequency switched-mode power supplies

#### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{RRM}$	repetitive peak reverse voltage		-	-	600	V
I <sub>F(AV)</sub>	average forward current	square-wave pulse; $\delta = 0.5$ ; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	-	4	Α
Static char	racteristics					
V <sub>F</sub>	forward voltage	$I_F = 4 \text{ A}$ ; $T_j = 25 \text{ °C}$ ; see <u>Figure 4</u>	-	-	1.28	V
Dynamic c	haracteristics					
t <sub>rr</sub>	reverse recovery time	$I_F = 1 \text{ A}$ ; $V_R = 30 \text{ V}$ ; $dI_F/dt = 50 \text{ A/µs}$ ; $T_j = 25 \text{ °C}$ ; Ramp Recovery; see Figure 5	-	33	65	ns
		$\begin{split} I_R &= 1 \text{ A; } I_F = 0.5 \text{ A;} \\ I_{R(meas)} &= 0.25 \text{ A; } T_j = 25 \text{ °C;} \\ \text{Step Recovery; see } \underline{\text{Figure 6}} \end{split}$	-	25	50	ns



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## 2. Pinning information

#### Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		v 14 .
2	А	anode	K a	K — A 001aaa020
			SOD141 (DO-201AD)	

## 3. Ordering information

#### Table 3. Ordering information

Type number	Package			
	Name	Description	Version	
NUR460	DO-201AD	Hermetically sealed plastic package; axial leaded; 2 leads	SOD141	

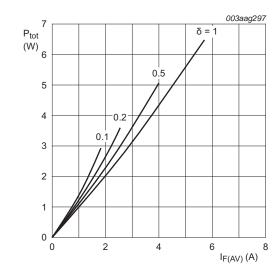
## 4. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

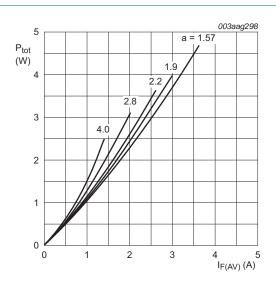
Symbol	Parameter	Conditions	Min	Max	Unit
$V_{RRM}$	repetitive peak reverse voltage		-	600	V
$V_{RWM}$	crest working reverse voltage		-	600	V
$V_R$	reverse voltage	DC	-	600	V
I <sub>F(AV)</sub>	average forward current	square-wave pulse; $\delta = 0.5$ ; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	4	A
I <sub>FRM</sub>	repetitive peak forward current	square-wave pulse; $\delta = 0.5$	-	8	Α
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 8.3 ms; sine-wave pulse; $T_{j(init)}$ = 25 °C; see <u>Figure 3</u>	-	110	Α
		$t_p$ = 10 ms; sine-wave pulse; $T_{j(init)}$ = 25 °C; see <u>Figure 3</u>	-	100	Α
T <sub>stg</sub>	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C

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$$\begin{split} I_{\textit{F(AV)}} = & I_{\textit{F(RMS)}} \times \sqrt{\pmb{\delta}} \\ V_{\text{O}} = & 0.968 \text{ V; R}_{\text{S}} = 0.036 \Omega \end{split}$$

Fig 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



a = form factor = 
$$I_{F(RMS)}/I_{F(AV)}$$
  
 $V_{O} = 0.968V$ ;  $R_{s} = 0.036\Omega$ 

Fig 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

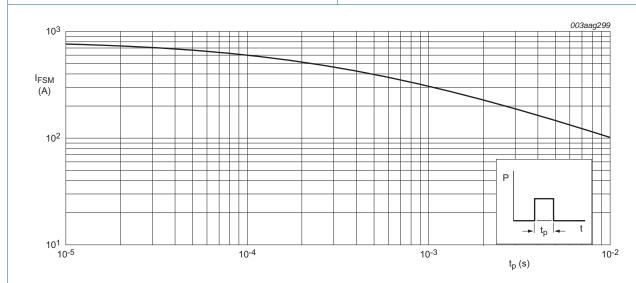


Fig 3. Non-repetitive peak forward current as a function of pulse width; square waveform; maximum values

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## 5. Thermal characteristics

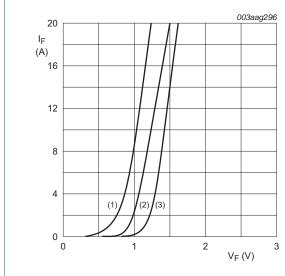
#### Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	-	55	-	K/W

## 6. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V <sub>F</sub>	forward voltage	$I_F = 4 \text{ A}$ ; $T_j = 25 \text{ °C}$ ; see Figure 4	-	-	1.28	V
		$I_F = 4 \text{ A}; T_j = 150 \text{ °C}; \text{ see } \frac{\text{Figure 4}}{\text{Minimum 1}}$	-	0.88	1.05	V
I <sub>R</sub>	reverse current	$V_R = 600 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-	50	μΑ
Dynamic	characteristics					
t <sub>rr</sub> reverse recovery time	$I_F = 1 \text{ A}$ ; $V_R = 30 \text{ V}$ ; $dI_F/dt = 50 \text{ A/}\mu\text{s}$ ; Ramp Recovery; $T_j$ 25 °C; see Figure 5	-	33	65	ns	
		$I_F = 0.5 \text{ A}$ ; $I_R = 1 \text{ A}$ ; Step Recovery; $I_{R(meas)} = 0.25 \text{ A}$ ; $T_j = 25 ^{\circ}\text{C}$ ; see Figure 6	-	25	50	ns



 $V_{0} = 0.968 \text{ V}; R_{s} = 0.036\Omega;$ 

(1)  $T_j = 150$  °C; typical value;

(2)  $T_j = 150$  °C; maximum value;

(3)  $T_i = 25$  °C; maximum value

Fig 4. Forward current as a function of forward voltage

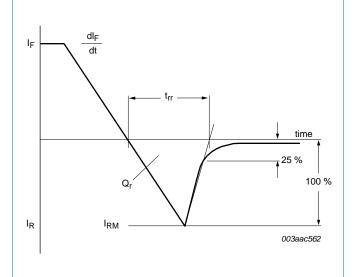
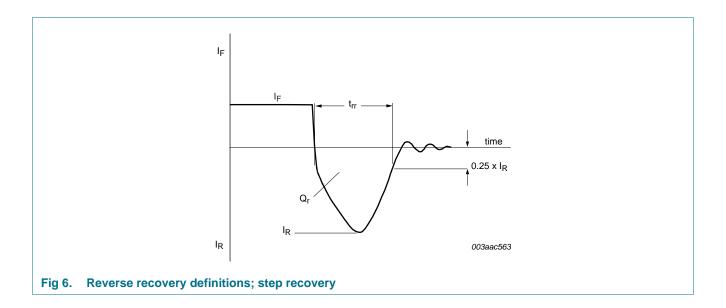


Fig 5. Reverse recovery definitions; ramp recovery

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## 7. Package outline

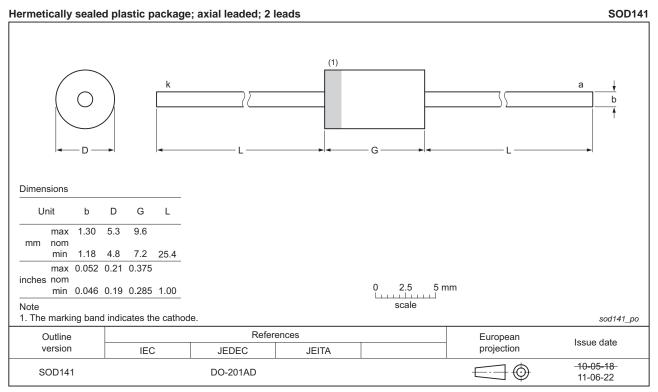


Fig 7. Package outline SOD141 (DO-201AD)

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## 8. Revision history

## Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
NUR460 v.2	20110720	Product data sheet	-	NUR460 v.1
Modifications:	<ul> <li>Various changes to</li> </ul>	content.		
NUR460 v.1	20110704	Product data sheet	-	-

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## 9. Legal information

#### 9.1 Data sheet status

Document status [1] [2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design
- [2] The term 'short data sheet' is explained in section "Definitions"
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